

Vishay Semiconductors

RoHS COMPLIANT

HALOGEN

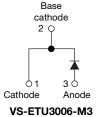
FREE

Ultrafast Rectifier, 8 A FRED Pt®





2L TO-220 FULL-PAK





VS-ETU3006FP-M3

| PRODUCT SUMMARY | | | | | |
|----------------------------------|--------------------------|--|--|--|--|
| Package | 2L TO-220AC, 2L TO-220FP | | | | |
| I _{F(AV)} | 30 A | | | | |
| V _R | 600 V | | | | |
| V _F at I _F | 1.15 V | | | | |
| t _{rr} (typ.) | 30 ns | | | | |
| T _J max. | 175 °C | | | | |
| Diode variation | Single die | | | | |

FEATURES

- Low forward voltage drop
- · Ultrafast soft recovery time
- 175 °C operating junction temperature
- · Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- True 2 pin package
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

Ultralow V_F , soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--|-----------------------------------|-------------------------|-------------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Peak repetitive reverse voltage | V _{RRM} | | 600 | V | | |
| Average restified femiliary current in DC | I _{F(AV)} | T _C = 130 °C | 30 | А | | |
| Average rectified forward current in DC FULL-PAK | | T _C = 72 °C | 30 | | | |
| Non-repetitive peak surge current | I _{FSM} | T _J = 25 °C | 200 | | | |
| Operating junction and storage temperatures | T _J , T _{Stg} | | -65 to +175 | °C | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|--|-------------------------------------|--|-----|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS MIN. TYP. MA | | | | UNITS | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | Ι _R = 100 μΑ | 600 | - | - | | |
| Forward voltage | V _F | I _F = 30 A | - | 1.4 | 2.0 | 2.0 V | |
| | | I _F = 30 A, T _J = 150 °C | - | 1.15 | 1.35 | | |
| Doverno lookago current | | $V_R = V_R$ rated | - | 0.02 | 30 | | |
| Reverse leakage current I _R | | T _J = 150 °C, V _R = V _R rated | = | 30 | 250 | μA | |
| Junction capacitance | C _T | V _R = 600 V | - | 20 | - | pF | |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | - | 8 | - | nH | |



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| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|---|------------------|---|--|------|------|-------|-------|
| PARAMETER | SYMBOL | TEST CO | MIN. | TYP. | MAX. | UNITS | |
| | | $I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A}$ | $I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ | | 30 | 45 | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | $I_F = 30 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$ | - | 45 | - | ns |
| | | T _J = 125 °C | | - | 100 | - | |
| Dools was assemt assemt | | T _J = 25 °C | | - | 5.6 | - | Α |
| Peak recovery current | I _{RRM} | T _J = 125 °C | | - | 10 | - | |
| Reverse recovery charge | | T _J = 25 °C | | - | 127 | = | nC |
| | Q _{rr} | T _J = 125 °C | | - | 580 | - | nC nC |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|--|-----------------------------------|--|----------|------|------------|------------------------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -65 | - | 175 | °C | |
| Thermal resistance, | В | | - | 0.84 | 1.3 | | |
| junction to case FULL-PAK | R_{thJC} | | - | 3.2 | 3.8 | | |
| Thermal resistance, junction to ambient | R _{thJA} | Typical socket mount | - | - | 70 | °C/W | |
| Typical thermal resistance, case to heatsink | R _{thCS} | Mounting surface, flat, smooth and greased | - | 0.5 | - | | |
| Weight | | | - | 2 | - | g | |
| Weight | | | - | 0.07 | - | oz. | |
| Mounting torque | | | 6 (5) | - | 12 (10) | kgf · cm (lbf · in) | |
| Madring dovice | | Case style 2L TO-220AC | ETU3006 | | - | | |
| Marking device | | Case style 2L TO-220 FULL-PAK | | ETU3 | 006FP | | |

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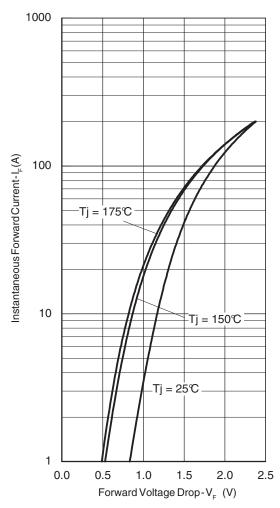


Fig. 1 - Typical Forward Voltage Drop Characteristics

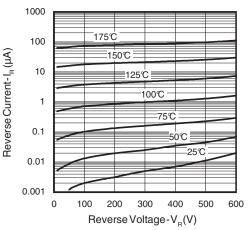


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

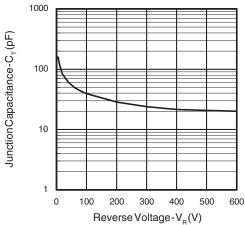


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

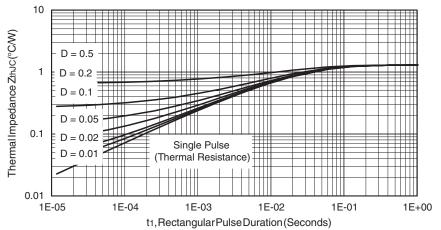


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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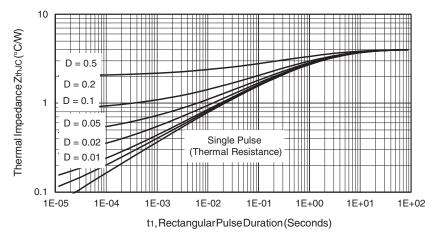


Fig. 5 - Maximum Thermal Impedance Z_{thJC} Characteristics (FULL-PAK)

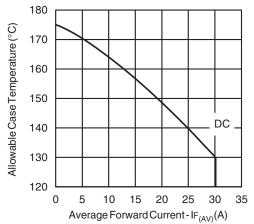


Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current

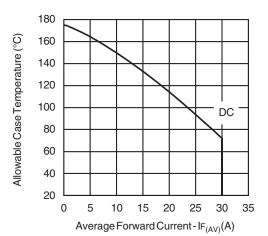


Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FULL-PAK)

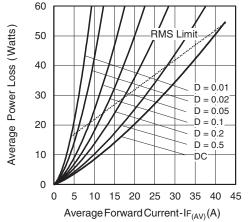


Fig. 8 - Forward Power Loss Characteristics

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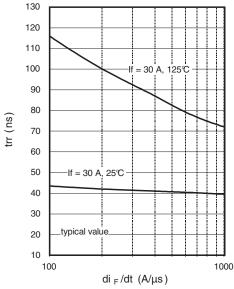


Fig. 9 - Typical Reverse Recovery vs. dl_F/dt

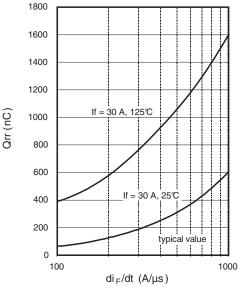


Fig. 10 - Typical Stored Charge vs. dl_F/dt

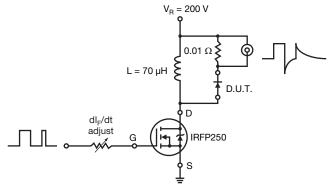
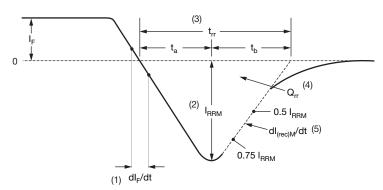


Fig. 11 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

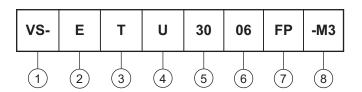
Fig. 12 - Reverse Recovery Waveform and Definitions

VS-ETU3006-M3, VS-ETU3006FP-M3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration:

E = single diode

3 - T = TO-220

U = hyperfast recovery time

Current code: 30 = 30 A

Voltage code: 06 = 600 V

7 - • None = TO-220

• FP = FULL-PAK

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

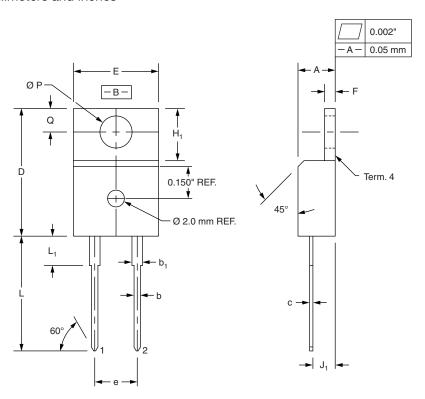
| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|-------------------|------------------------|-------------------------|--|--|--|
| PREFERRED P/N | QUANTITY PER TUBE | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | |
| VS-ETU3006-M3 | 50 | 1000 | Antistatic plastic tube | | | |
| VS-ETU3006FP-M3 | 50 | 1000 | Antistatic plastic tube | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|----------------------------|--------------------|--------------------------|--|--|--|
| Dimensions | 2L TO-220AC | www.vishay.com/doc?95259 | | | |
| Dimensions | 2L TO-220 FULL-PAK | www.vishay.com/doc?95260 | | | |
| Part marking information | 2L TO-220AC | www.vishay.com/doc?95391 | | | |
| Fait marking information | 2L TO-220 FULL-PAK | www.vishay.com/doc?95392 | | | |

Vishay Semiconductors

True 2 Pin TO-220

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIM | METERS | INC | HES |
|--------------------|--------|--------|-------|-------|
| STMBOL | MIN. | MAX. | MIN. | MAX. |
| А | 4.32 | 4.57 | 0.170 | 0.180 |
| b | 0.71 | 0.91 | 0.028 | 0.036 |
| b ₁ | 1.15 | 1.39 | 0.045 | 0.055 |
| С | 0.36 | 0.53 | 0.014 | 0.021 |
| D | 14.99 | 15.49 | 0.590 | 0.610 |
| E | 10.04 | 10.41 | 0.395 | 0.410 |
| е | 5.08 | BSC | 0.200 | BSC |
| F | 1.22 | 1.37 | 0.048 | 0.054 |
| H ₁ | 5.97 | 6.47 | 0.235 | 0.255 |
| J ₁ | 2.54 | 2.79 | 0.100 | 0.110 |
| L | 13.47 | 13.97 | 0.530 | 0.550 |
| L ₁ (1) | 3.31 | 3.81 | 0.130 | 0.150 |
| Ø P | 3.79 | 3.88 | 0.149 | 0.153 |
| Q | 2.60 | 2.84 | 0.102 | 0.112 |

Notes

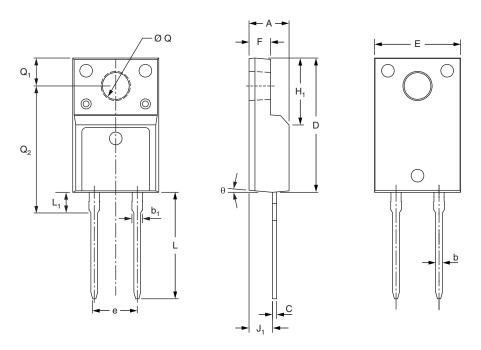
- $^{(1)}$ Lead dimension and finish uncontrolled in L_1
- These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87
- Controling dimension: Inch



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True 2 Pin TO-220 FULL-PAK

DIMENSIONS in millimeters and inches



| CVMDOL | MILLIM | METERS | INCH | IES |
|----------------|--------|--------|----------|--------|
| SYMBOL | MIN. | MAX. | MIN. | MAX. |
| A | 4.53 | 4.93 | 0.178 | 0.194 |
| b | 0.71 | 0.91 | 0.028 | 0.036 |
| b ₁ | 1.15 | 1.39 | 0.045 | 0.055 |
| С | 0.36 | 0.53 | 0.014 | 0.021 |
| D | 15.67 | 16.07 | 0.617 | 0.633 |
| E | 9.96 | 10.36 | 0.392 | 0.408 |
| е | 5.08 t | ypical | 0.200 ty | ypical |
| F | 2.34 | 2.74 | 0.092 | 0.107 |
| H ₁ | 6.50 | 6.90 | 0.256 | 0.272 |
| J ₁ | 2.56 | 2.96 | 0.101 | 0.117 |
| L | 12.78 | 13.18 | 0.503 | 0.519 |
| L ₁ | 2.23 | 2.63 | 0.088 | 0.104 |
| ØQ | 2.98 | 3.38 | 0.117 | 0.133 |
| Q ₁ | 3.10 | 3.50 | 0.122 | 0.138 |
| Q_2 | 14.80 | 15.20 | 0.583 | 0.598 |
| θ | 0° | 5° | 0° | 5° |



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